

# 17210

**16172**

**2 Hours / 50 Marks**

Seat No.

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- Instructions :**
- (1) All Questions are *compulsory*.
  - (2) Answer each next main Question on a new page.
  - (3) Illustrate your answers with neat sketches wherever necessary.
  - (4) Figures to the right indicate full marks.
  - (5) Use of Non-programmable Electronic Pocket Calculator is permissible.
  - (6) Mobile Phone, Pager and any other Electronic Communication devices are not permissible in Examination Hall.

**Marks**

**1. Attempt any NINE of the following :**

**18**

- (a) State Ohm's law. Give meaning of the symbols used.
- (b) State the principle of potentiometer device.
- (c) Draw a neat diagram of Wheatstone's Network.
- (d) Write the factors on which capacity of parallel plate capacitor depends.
- (e) Define One Farad.
- (f) Draw a neat labelled diagram showing capacitors connected in parallel combination.
- (g) Draw the energy band diagram for conductors and semiconductors.
- (h) State the principle of photodiode and draw its symbol.
- (i) Draw the circuit diagram of reverse biased PN junction diode.
- (j) An accelerated electron emits a quantum of radiation with frequency  $8 \times 10^8$  Hz. Calculate the energy of electron. Given :  $h = 6.62 \times 10^{-34}$  Js.
- (k) Give the full form of LASER.
- (l) Name one zero dimensional and one dimensional nano material.

**2. Attempt any FOUR of the following :****16**

- (a) The specific resistance of the material of a wire is  $2.81 \times 10^{-7} \Omega\text{m}$ . If the resistance of the wire is  $2.1 \Omega$  and its radius is  $0.8 \text{ mm}$ , calculate the length of the wire.
- (b) (i) State the principle of the potentiometer.  
(ii) Define potential gradient :
- (c) Find the area of parallel-plate condenser if its capacitance is  $3 \mu\text{F}$ , distance between the two plates is  $0.04 \text{ mm}$ , dielectric constant is  $6$  and  $\epsilon_0 = 8.9 \times 10^{-12} \text{ SI unit}$ .
- (d) Explain forward biased PN junction diode. Draw its I-V characteristics.
- (e) Differentiate N-type and P-type semiconductor.
- (f) State four applications of LDR.

**3. Attempt any FOUR of the following :****16**

- (a) Draw a neat labelled diagram of photocell and state two properties of photons.
- (b) Explain the production of X-ray's using Coolidge tube.
- (c) State four applications of X-ray's.
- (d) Calculate the minimum wavelength and maximum frequency of X-ray's produced by an X-ray tube working at  $40 \text{ kV}$ .

Given :  $h = 6.62 \times 10^{-34} \text{ Js}$

$$c = 3 \times 10^8 \text{ m/s}$$

$$e^- = 1.6 \times 10^{-19} \text{ C}$$

- (e) State the engineering applications of LASER.
  - (f) State four applications of nano material in engineering field.
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